

General-purpose Operational Amplifiers / Comparators

SIGNATURE SERIES Operational Amplifiers



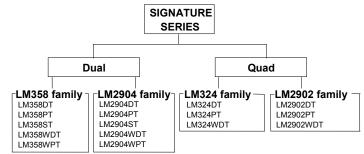
LM358DT/PT/ST/WDT/WPT,LM2904DT/PT/ST/WDT/WPT LM324DT/PT/WDT,LM2902DT/PT/WDT

No.10094EAT05

Description

The Universal Standard family LM358 / 324, LM2904 / 2902 monolithic ICs integrate two independent op-amps and phase compensation capacitors on a single chip

and feature high-gain, low power consumption, and an operating voltage range of 3[V] to 32[V] (single power supply.)



Features

1) Operating temperature range

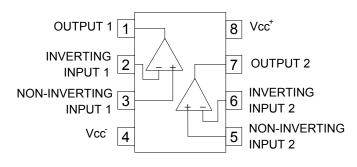
Commercial Grade LM358/324 family : $0[^{\circ}C]$ to + $70[^{\circ}C]$ Extended Industrial Grade LM2904/2902 family : $-40[^{\circ}C]$ to +125 $[^{\circ}C]$

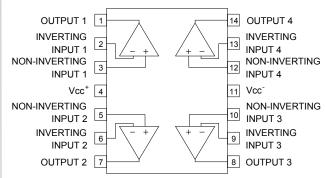
2) Wide operating supply voltage +3[V] to +32[V] (single supply) ±1.5[V] to ±16[V] (dual supply)

3) Low supply current

- 4) Common-mode input voltage range including ground
- 5) Differential input voltage range equal to maximum rated supply voltage
- 6) High large signal voltage gain
- 7) Wide output voltage range

●Pin Assignment





SO package8

TSSOP8

Mini SO8

SO package14

TSSOP14

LM358DT LM358WDT LM2904DT LM2904WDT LM358PT LM358WPT LM2904PT LM2904WPT LM358ST LM2904ST

LM324WDT LM2902DT LM2902WDT LM324PT LM2902PT ● Absolute Maximum Ratings (Ta=25[°C])

Parameter	Symbol	Rating									
Farameter	Syllibol	LM358 family	LM324 family	LM2904 family	LM2902 family	Unit					
Supply Voltage	VDD	+32									
Operating Temperature Range	Topr	0 to +70 -40 to +125									
Storage Temperature Range	Tstg	-65 to +150									
Input Common-mode Voltage	VICM	-0.3 to +32						-0.3 to +32			V
Maximum Junction Temperature	Tjmax	+150									

Electric Characteristics

OLM358,LM324 family(Unless otherwise specified, Vcc⁺=+5[V], Vcc⁻=0[V])

		Limit										
Parameter	Symbol	Temperature range	LN	M358 fan	nily	LM324 family			Unit	Conditions		
		_	Min.	Тур.	Max.	Min.	Тур.	Max.				
Input Offset Voltage (*1)	VIO	25°C	-	2	7	_	_	7	mV	VO=1.4[V],RS=0[Ω] 5[V]< Vcc ⁺ <30[V]	2	
par ellest relage (1)		Full range	-	-	9	_	_	9		0 <vic< vcc<sup="">+-1.5[V]</vic<>		
Input Offset Current (*1)	IIO	25°C	_	2	30	_	2	30	nA	VO=1.4[V]	2	
, , ,		Full range	_	_	_	_	_	100				
Input Bias Current (*1)	IIB	25°C	_	20	150		20	150	nA	VO=1.4[V]	2	
		Full range	_	_	200		_	300		Vcc ⁺ =15[V]		
Large Signal Voltage Gain	AVD	25°C	25	100	_	25	100	_	V/mV	VO=1.4[V] to 11.4[V] RL=2[kΩ]	2	
Supply Voltage Rejection Ratio	SVR	25°C	65	100	_	65	110	-	dB	RS≦10[kΩ]	2	
Cuppiy Voltage Hojection Hatte	OVIX	Full range	65	_	_	65	_	_	u _D	Vcc ⁺ =5[V] to 30[V]		
		25°C	-	_	_	_	0.7	1.2	,	Vcc ⁺ =5[V],No Load		
Supply Current (All Amp)	ICC	25°C	_	_	_	_	1.5	3	mA	Vcc ⁺ =30[V],No Load	3	
Supply Sullent (unvulle)		Full range	-	0.7	1.2	_	8.0	3		Vcc ⁺ =5[V],No Load		
		Full range	_	_	2	_	1.5	3		Vcc ⁺ =30[V],No Load		
Input Common-mode Voltage Range	VICM	25°C	_	_	Vcc ⁺ -1.5	_	_	Vcc ⁺ -1.5	V	Vcc*=30[V]	2	
		Full range	_	_	Vcc ⁺ -2.0	_	_	Vcc ⁺ -2.0	·	.00 00[.]		
Common-mode Rejection Ratio	CMR	25°C	70	85	_	70	80	_	dB	RS≦10[kΩ]	2	
	0	Full range	60	_	_	60	_	_				
Output Short Circuit Current (*2)	Isource	25°C	20	40	60	20	40	70	mA	Vcc ⁺ =15[V],VO=+2[V] VID=+1[V]	3	
		0-	10	20	_	10	20	_	mA	VO=+2[V], Vcc ⁺ =15[V],VID=-1[V]		
Output Sink Current (*2)	Isink	25°C	12	50	_	12	50	_	μA	VO=+0.2[V],	- 3	
		25°C	0	_	Vcc⁺-1.5		_	_		Vcc ⁺ =15[V] ,VID=-1[V]		
Output Voltage Swing	Vopp	Full range	0	_	Vcc⁺-2.0		_	_	V	RL=2[k Ω]	3	
		25°C	27	28	_	27	28	_				
High Level Output Voltage	VOH	Full range	27	_	_	27	_	_	V	$Vcc^{\dagger}=30[V],RL=10[k\Omega]$	3	
		25°C	_	5	20		5	20				
Low Level Output Voltage	VOL	Full range	-	_	20	_	_	20	mV	RL=10[kΩ]	3	
Slew Rate	SR	25℃	_	0.6	_	_	0.4	_	V/µs	RL=2[kΩ],CL=100[pF], Vcc*=15[V] VI=0.5[V] to 3[V], Unity Gain	3	
Gain Bandwidth Product	GBP	25°C	-	1.1	_	_	1.3	_	MHz	Vcc ^f =30[V],RL=2[kΩ], CL=100[pF] VIN=10[mV],f=100[kHz]	3	
Total Harmonic Distortion	THD	25°C	-	0.02	_	-	0.015	_	%	f=1[kHz],AV=20[dB] RL=2[kΩ] CL=100[pF],VO=2[Vpp]	3	
Input Equivalent Noise Voltage	en	25°C	ı	55	_	-	40	_	nV/√Hz	f=1[kHz],RS=100[Ω] Vcc ⁺ =30[V]	3	
Input Offset Voltage Drift	DVIO	_	ı	7	_	_	7	_	μV/°C	_	-	
Input Offset Current Drift	DIIO	_	-	10	_	_	10	_	pA/°C	_	-	
Channel Separation	VO1/VO2	25°C	1	120	_	_	120	_	dB	1[kHz]≦f≦20[kHz]	ŧ	
	1	l		I	1		1	1		l .	1	

^(*1) Absolute value

^(*2) Under high temperatures, please consider the power dissipation when selecting the output current.

When output terminal is continuously shorted the output current reduces the internal temperature by flushing.

OLM2904,LM2902 family(Unless otherwise specified, Vcc+=+5[V], Vcc-=0[V])

Parameter	Symbol	Temperature	Limit LM2904 family LM2902 family						Unit	Conditions		
		range	Min.	Тур.	Max.	Min.	Тур.	Max.			No	
land Offert \/alterna (*2)	\/IO	25°C	_	2	7	_	2	7	\/	VO-4 4D (I		
Input Offset Voltage (*3)	VIO	Full range	_	_	9	_	_	9	mV	VO=1.4[V]	2	
Input Offset Current (*3)	IIO	25°C	_	2	50	_	2	30	nA	VO=1.4[V]	2	
input Onset Current (3)	110	Full range	_	_	200		_	200	iκ	VO=1.4[V]		
Input Bias Current (*3)	IIB	25°C	_	20	150	_	20	150	nA	VO=1.4[V]	2	
mput bias ourrent (o)	115	Full range	_	_	200	_	_	300	11/ (
Large Signal Voltage Gain	AVD	25°C	25	100	_	25	100	_	V/mV	Vcc ⁺ =15[V] VO=1.4[V] to 11.4[V] RL=2[kΩ]	2	
Sumply Voltage Rejection Ratio	SVR	25°C	65	100	-	65	110	_	dB	RS≦10[kΩ]	2	
Supply Voltage Rejection Ratio	SVK	Full range	65	_	-	65	_	_	ив	K2≅ 10[K12]	4	
		25°C	-	0.7	1.2	_	0.7	1.2		Vcc ⁺ =5[V],No Lord		
Consider Comment (All Assa)	100	25°C	_	_	_	_	1.5	3	A	Vcc ⁺ =30[V],No Lord	٦,	
Supply Current (All Amp)	ICC	Full range	-	_	2	_	0.8	1.2	mA	Vcc ⁺ =5[V],No Lord	3	
		Full range	_	_	-	_	1.5	3		Vcc ⁺ =30[V],No Lord		
		25°C	_	_	Vcc⁺-1.5	_	_	Vcc⁺-1.5	.,	\(\dagger{1}{2} \cdot \	2	
nput Common-mode Voltage Range	VICM	Full range	_	_	Vcc ⁺ -2.0	_	_	Vcc⁺-2.0	V	Vcc ⁺ =30[V]	2	
		25°C	70	85	_	70	80	_				
Common-mode Rejection Ratio	CMR	Full range	60	_	-	60	_	_	dB	RS=10[kΩ]		
Output Short Circuit Current (*4)	Isource	25°C	20	40	60	20	40	70	mA	Vcc ⁺ =+15[V],VO=+2[V] VID=+1[V]	;	
Output Sink Current (*4)	Isink	25°C	10	20	_	10	20	_	mA	VO=2[V],Vcc ⁺ =+5[V] VID=-1[V]	3	
			12	50	_	12	50	_	μΑ	VO=+0.2[V], Vcc ⁺ =+15[V],VID=-1[V]		
Output Valtage Swing	Vonn	25°C	0	_	Vcc⁺-1.5	_	_	_	٧			
Output Voltage Swing	Vopp	Full range	0	_	Vcc⁺-2.0	_	_	_	V	RL=2[kΩ]	;	
High Level Output Voltage	VOH	25°C	27	_	-	27	28	-	٧	$Vcc^{+}=30[V],RL=10[k\Omega]$		
High Level Output voltage	VOH	Full range	27	28	-	27	_	_	V	$Vcc^{+}=30[V],RL=10[k\Omega]$	- ;	
Low Level Output Voltage	VOL	25°C	_	5	20	_	5	20	mV	RL=10[kΩ]		
Low Level Output voltage	VOL	Full range	_	_	20	-	_	20	IIIV		,	
Slew Rate	SR	25°C	_	0.6	_	-	0.4	_	V/µs	RL=2[k Ω],CL=100[pF], Unity Gain VI=0.5[V] to 3[V] Vcc ⁺ =1.5[V]	(
Gain Bandwidth Product	GBP	25°C	_	1.1	_	-	1.3	_	MHz	Vcc ⁺ =30[V],RL=2[kΩ] CL=100[pF] VIN=10[mV]	;	
Total Harmonic Distortion	THD	25°C	_	0.02	_	_	0.015	_	%	f=1[kHz],AV=20[dB] RL=2[kΩ] CL=100[pF], Vcc ⁺ =30[V],VO=2[Vpp]	;	
nput Equivalent Noise Voltage	en	25°C	_	_	_	-	40	_	nV/ √ Hz	f=1[kHz],RS=100[Ω] Vcc ⁺ =30[V]	;	
nput Offset Voltage Drift	DVIO	I	_	7	_	-	7	_	μV/°C	-	-	
nput Offset Current Drift	DIIO	-	_	10	_	-	10	_	pA/°C	-	-	
Channel Separation	VO1/VO2	25°C	_	120	_	_	120	_	dB	1[kHz]≦f≦20[kHz]		

^(*3) Absolute value

^(*4) Under high temperatures, please consider the power dissipation when selecting the output current.

When the output terminal is continuously shorted the output current reduces the internal temperature by flushing.

●Circuit Diagram

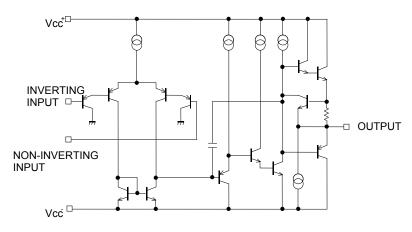


Fig.1 Circuit Diagram (each Op-Amp)

■ Measurement Circuit 1 NULL Method Measurement Condition

Vcc⁺, Vcc⁻, EK, Vicm Unit: [V]

		0.4	04 00		LM358/LM324 family					LM2904/LM2902 family					
Parameter	VF	S1	S2	S3	Vcc+	Vcc-	EK	Vicm	Vcc+	Vcc-	EK	Vicm	Calculation		
Input Offset Voltage	VF1	ON	ON	OFF	5 to 30	0	-1.4	0	5 to 30	0	-1.4	0	1		
Input Offset Current	VF2	OFF	OFF	OFF	5	0	-1.4	0	5	0	-1.4	0	2		
Input Bias Current	VF3	OFF	F ON	OFF	5	0	-1.4	0	5	0	-1.4	0	- 3		
Input Bias Current	VF4	ON	OFF		5	0	-1.4	0	5	0	-1.4	0			
Large Signal Voltage Gain	VF5		ON ON	ON ON	15	0	-1.4	0	15	0	-1.4	0	4		
Large Signal Voltage Gain	VF6	ON		JN ON	15	0	-11.4	0	15	0	-11.4	0	4		
Common-mode Rejection Ratio	VF7	ON	N ON	OFF	5	0	-1.4	0	5	0	-1.4	0	5		
Common-mode Rejection Ratio	VF8	ON			5	0	-1.4	3.5	5	0	-1.4	3.5	5		
Supply Voltage Rejection Ratio	VF9	ON	N ON	OFF	5	0	-1.4	0	5	0	-1.4	0	6		
Supply Voltage Rejection Ratio	VF10	ON	ON		OFF	OFF	OFF	30	0	-1.4	0	30	0	-1.4	0

-Calculation-

1. Input Offset Voltage (VIO)

$$Vio = \frac{|VF1|}{1+ Rf/Rs} [V]$$

2. Input Offset Current (IIO)

$$lio = \frac{\left| VF2 - VF1 \right|}{Ri(1+Rf/Rs)} [A]$$

3. Input Bias Current (IIB)

$$Ib = \frac{\left| VF4 - VF3 \right|}{2 \times Ri (1 + Rf / Rs)} [A]$$

4. Large Signal Voltage Gain (AVD)

$$AV = 20 \times Log \frac{10 \times (1 + Rf/Rs)}{|VF6 - VF5|} [dB]$$

5.Common-mode Rejection Ration (CMRR)

CMRR = 20× Log
$$\frac{3.5 \times (1+ Rf/ Rs)}{|VF8-VF7|}$$
 [dB]

6. Supply Voltage Rejection Ration (SVR)

$$PSRR = 20 \times Log \frac{\triangle Vcc^{+} \times (1 + Rf/Rs)}{VF10 - VF9} [dB]$$
$$\triangle Vcc^{+} = 25V$$

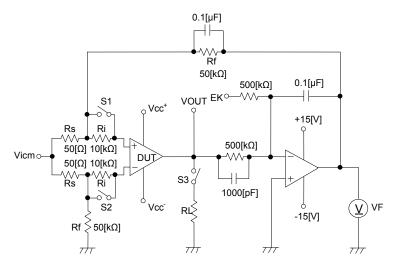


Fig.2 Measurement circuit1 (Each Op-Amps)

Measurement circuit2 Switch condition

SW No.	SW 1	SW 2	SW 3	SW 4	SW 5	SW 6	SW 7	SW 8	SW 9	SW 10	SW 11	SW 12	SW 13	SW 14	SW 15
Supply Current	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	OFF
High level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF
Low level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	ON	OFF
Output source current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
Output sink current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
Slew Rate	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	OFF	OFF	OFF
Gain band width product	OFF	ON	OFF	OFF	OFF	ON	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	OFF
Equivalent input noise voltage	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF	OFF

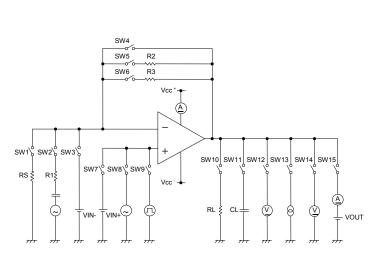


Fig.3 Measurement circuit2 (Each Op-Amps)

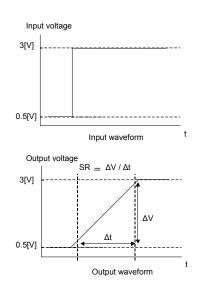


Fig.4 Slew Rate Input Waveform

● Measurement Circuit3 Channel Separation

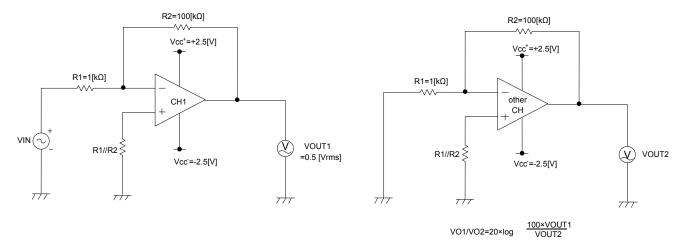


Fig.5 Measurement Circuit3

Description of Electrical Characteristics

Described below are descriptions of the relevant electrical terms

Please note that item names, symbols and their meanings may differ from those on another manufacturer's documents.

1. Absolute maximum ratings

The absolute maximum ratings are values that should never be exceeded, since doing so may result in deterioration of electrical characteristics or damage to the part itself as well as peripheral components.

1.1 Power supply voltage (Vcc⁺/Vcc⁻)

Expresses the maximum voltage that can be supplied between the positive and negative supply terminals without causing deterioration of the electrical characteristics or destruction of the internal circuitry.

1.2 Differential input voltage (VID)

Indicates the maximum voltage that can be supplied between the non-inverting and inverting terminals without damaging the IC.

1.3 Input common-mode voltage range (VICM)

Signifies the maximum voltage that can be supplied to non-inverting and inverting terminals without causing deterioration of the characteristics or damage to the IC itself. Normal operation is not guaranteed within the common-mode voltage range of the maximum ratings - use within the input common-mode voltage range of the electric characteristics instead

1.4 Operating and storage temperature ranges (Topr,Tstg)

The operating temperature range indicates the temperature range within which the IC can operate. The higher the ambient temperature, the lower the power consumption of the IC. The storage temperature range denotes the range of temperatures the IC can be stored under without causing excessive deterioration of the electrical characteristics.

1.5 Power dissipation (Pd)

Indicates the power that can be consumed by a particular mounted board at ambient temperature (25°C). For packaged products, Pd is determined by the maximum junction temperature and the thermal resistance

2. Electrical characteristics

2.1 Input offset voltage (VIO)

Signifies the voltage difference between the non-inverting and inverting terminals. It can be thought of as the input voltage difference required for setting the output voltage to 0 V.

2.2 Input offset voltage drift (DVIO)

Denotes the ratio of the input offset voltage fluctuation to the ambient temperature fluctuation.

Indicates the difference of input bias current between the non-inverting and inverting terminals.

2.4 Input offset current drift (DIIO)

Signifies the ratio of the input offset current fluctuation to the ambient temperature fluctuation.

2.5 Input bias current (IIB)

Denotes the current that flows into or out of the input terminal, it is defined by the average of the input bias current at the non-inverting terminal and the input bias current at the inverting terminal.

2.6 Circuit current (ICC)

Indicates the current of the IC itself that flows under specified conditions and during no-load steady state.

2.7 High level output voltage/low level output voltage (VOH/VOL)
Signifying the voltage range that can be output under specified load conditions, it is in general divided into high level output voltage and low level output voltage. High level output voltage indicates the upper limit of the output voltage, while low level output voltage the lower limit.

2.8 Large signal voltage gain (AVD)

The amplifying rate (gain) of the output voltage against the voltage difference between non-inverting and inverting terminals, it is (normally) the amplifying rate (gain) with respect to DC voltage.

AVD = (output voltage fluctuation) / (input offset fluctuation)

2.9 Input common-mode voltage range (VICM)

Indicates the input voltage range under which the IC operates normally.

2.10 Common-mode rejection ratio (CMRR)

Signifies the ratio of fluctuation of the input offset voltage when the in-phase input voltage is changed (DC fluctuation).

CMRR = (change in input common-mode voltage) / (input offset fluctuation)

2.11 Power supply rejection ratio (SVR)

Denotes the ratio of fluctuation of the input offset voltage when supply voltage is changed (DC fluctuation).

SVR = (change in power supply voltage) / (input offset fluctuation)

2.12 Output source current/ output sink current (IOH/IOL)

The maximum current that can be output under specific output conditions, it is divided into output source current and output sink current. The output source current indicates the current flowing out of the IC, and the output sink current the current flowing into the IC.

2.13 Channel separation (VO1/VO2)

Expresses the amount of fluctuation of the input offset voltage or output voltage with respect to the change in the output voltage of a driven channel.

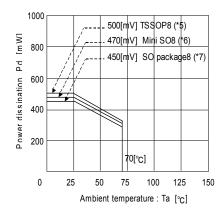
2.14 Slew rate (SR)

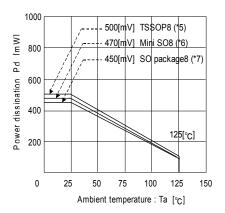
Indicates the time fluctuation ratio of the output voltage when an input step signal is supplied

2.15 Gain bandwidth product (GBP)

The product of the specified signal frequency and the gain of the op-amp at such frequency, it gives the approximate value of the frequency where the gain of the op-amp is 1 (maximum frequency, and unity gain frequency).

Derating curves





LM358DT/PT/ST/WDT/WPT

LM2904DT/PT/ST/WDT/WPT

Power Dissipation

Package	Pd[W]	θja [°C/W]
SO Package8 (*7)	450	3.6
TSSOP8 (*5)	500	4.0
Mini SO8 (*6)	470	3.76

 θ ja = (Tj-Ta)/Pd[°C/W]

Fig.6 Derating Curves

Precautions

1) Unused circuits

When there are unused circuits, it is recommended that they be connected as in Fig.7, setting the non-inverting input terminal to a potential within the in-phase input voltage range (VICM).

2) Input terminal voltage

 $\stackrel{.}{\text{Applying}}$ Vcc $^{-}$ + $32\overset{..}{\text{V}}$ to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, irrespective of

the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

3) Power supply (single / dual)

The op-amp operates when the voltage supplied is between Vcc⁺ and Vcc⁻. Therefore, the single supply op-mp can be used as a dual supply op-amp as well.

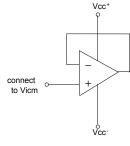


Fig.7 Disable circuit example

4) Power dissipation (Pd)

Using the unit in excess of the rated power dissipation may cause deterioration in electrical characteristics due to the rise in chip temperature, including reduced current capability. Therefore, please take into consideration the power dissipation (Pd) under actual operating conditions and apply a sufficient margin in thermal design. Refer to the thermal derating curves for more information.

5) Short-circuit between pins and erroneous mounting

Incorrect mounting may damage the IC. In addition, the presence of foreign substances between the outputs, the output and the power supply, or the output and Vcc may result in IC destruction.

6) Operation in a strong electromagnetic field

Operation in a strong electromagnetic field may cause malfunctions.

7) Radiation

This IC is not designed to withstand radiation.

8) IC handing

Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuation of the electrical characteristics due to piezoelectric (piezo) effects.

9) IC operation

The output stage of the IC is configured using Class C push-pull circuits. Therefore, when the load resistor is connected to the middle potential of Vcc[†] and Vcc[†], crossover distortion occurs at the changeover between discharging and charging of the output current. Connecting a resistor between the output terminal and Vcc[†], and increasing the bias current for Class A operation will suppress crossover distortion.

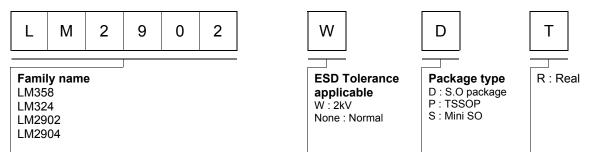
10) Board inspection

Connecting a capacitor to a pin with low impedance may stress the IC. Therefore, discharging the capacitor after every process is recommended. In addition, when attaching and detaching the jig during the inspection phase, ensure that the power is turned OFF before inspection and removal. Furthermore, please take measures against ESD in the assembly process as well as during transportation and storage.

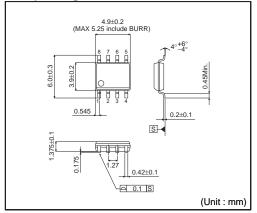
11) Output capacitor

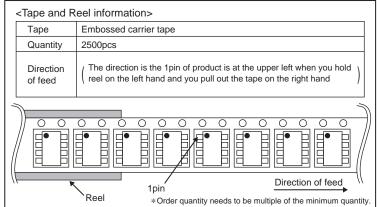
Discharge of the external output capacitor to Vcc⁺ is possible via internal parasitic elements when Vcc⁺ is shorted to Vcc⁻, causing damage to the internal circuitry due to thermal stress. Therefore, when using this IC in circuits where oscillation due to output capacitive load does not occur, such as in voltage comparators, use an output capacitor with a capacitance less than 0.1μF.

Ordering part number

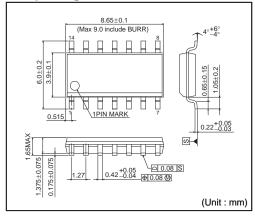


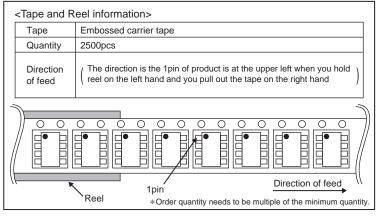
S.O package8



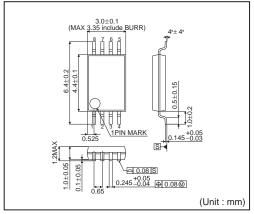


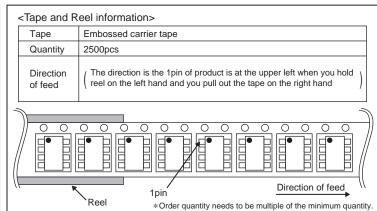
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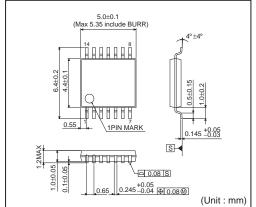


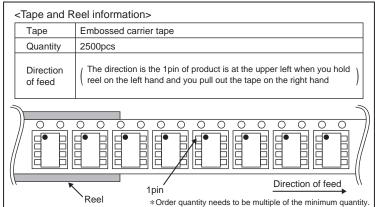
TSSOP8



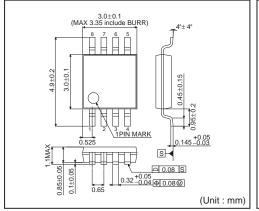


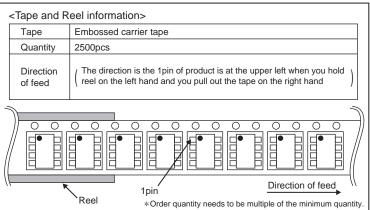
TSSOP14





Mini SO8





Notes

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